

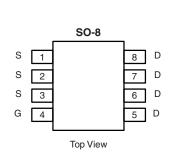
# SSG4472N-VB Datasheet N-Channel 200-V (D-S) MOSFET

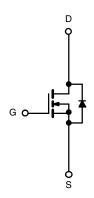
PRODUCT SUMMARY				
V <sub>DS</sub> (V)	$R_{DS(on)}\left(\Omega\right)$	I <sub>D</sub> (A)		
200	0.065 at V <sub>GS</sub> = 10 V	5.2		
	0.072 at V <sub>GS</sub> = 6.0 V	4.1		

#### **FEATURES**

- Halogen-free According to IEC 61249-2-21 Definition
- Trench Power MOSFETs
- Compliant to RoHS Directive 2002/95/EC







N-Channel MOSFET

<b>ABSOLUTE MAXIMUM RATINGS</b>	T <sub>A</sub> = 25 °C, unle	ss otherwise r	noted		
Parameter		Symbol	10 s	Steady State	Unit
Drain-Source Voltage		V <sub>DS</sub>	200		V
Gate-Source Voltage		$V_{GS}$	± 20		V
Continuo Dunio Cumant /T 150 00\8	T <sub>A</sub> = 25 °C	I <sub>D</sub>	5.2	3.35	
Continuous Drain Current (T <sub>J</sub> = 150 °C) <sup>a</sup>	T <sub>A</sub> = 70 °C		4.6	2.7	
Pulsed Drain Current		I <sub>DM</sub>	40		Α
Avalanch Current	L = 0.1 mH	I <sub>AS</sub>	15		
Continuous Source Current (Diode Conduction) <sup>a</sup>		I <sub>S</sub>	2.6	1.3	
M ·	T <sub>A</sub> = 25 °C	P <sub>D</sub>	3.1	1.56	W
Maximum Power Dissipation <sup>a</sup>	T <sub>A</sub> = 70 °C	гD	2.0	1.0	VV
Operating Junction and Storage Temperature Range		T <sub>J</sub> , T <sub>stg</sub>	- 55	to 150	°C

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
Martine Landing to Australia	t ≤ 10 s	R <sub>thJA</sub>	33	40		
Maximum Junction-to-Ambient <sup>a</sup>	Steady State	' 'thJA	65	80	°C/W	
Maximum Junction-to-Foot (Drain)	Steady State	$R_{thJF}$	17	21		

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

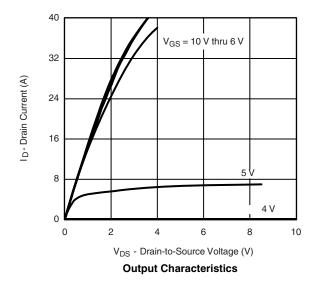


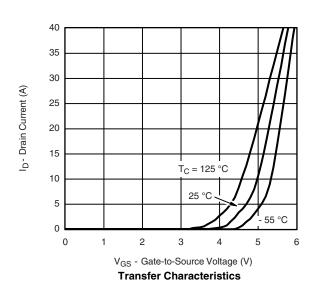
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2.0			V	
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zara Cata Valtaga Drain Current	1	V <sub>DS</sub> = 160 V, V <sub>GS</sub> = 0 V		1			
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> = 160 V, V <sub>GS</sub> = 0 V, T <sub>J</sub> = 55 °C			5	μΑ	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	40			Α	
	D	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 4.0 A		0.065			
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS} = 6.0 \text{ V}, I_D = 4.0 \text{ A}$		0.072		Ω	
Forward Transconductance <sup>a</sup>	9 <sub>fs</sub>	$V_{DS} = 15 \text{ V}, I_{D} = 5 \text{ A}$		19		S	
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	$I_S = 2.8 \text{ A}, V_{GS} = 0 \text{ V}$		0.75	1.2	V	
Dynamic <sup>b</sup>				1			
Total Gate Charge	$Q_g$			34	42		
Gate-Source Charge	$Q_{gs}$	$V_{DS} = 100 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 4.0 \text{ A}$		7.5		nC	
Gate-Drain Charge	Q <sub>gd</sub>			12.0			
Gate Resistance	$R_{g}$		0.2	0.85	1.3	Ω	
Turn-On Delay Time	t <sub>d(on)</sub>			14	20		
Rise Time	t <sub>r</sub>	$V_{DD}$ = 100 V, $R_L$ = 25 $\Omega$		20	30		
Turn-Off Delay Time	t <sub>d(off)</sub>	$I_D \cong 4.0 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 6 \Omega$		32	50	ns	
Fall Time	t <sub>f</sub>			25	35		
Source-Drain Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 2.8 A, dI/dt = 100 A/μs		70	100		

- Notes: a. Pulse test; pulse width  $\leq$  300  $\mu$ s, duty cycle  $\leq$  2 %. b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

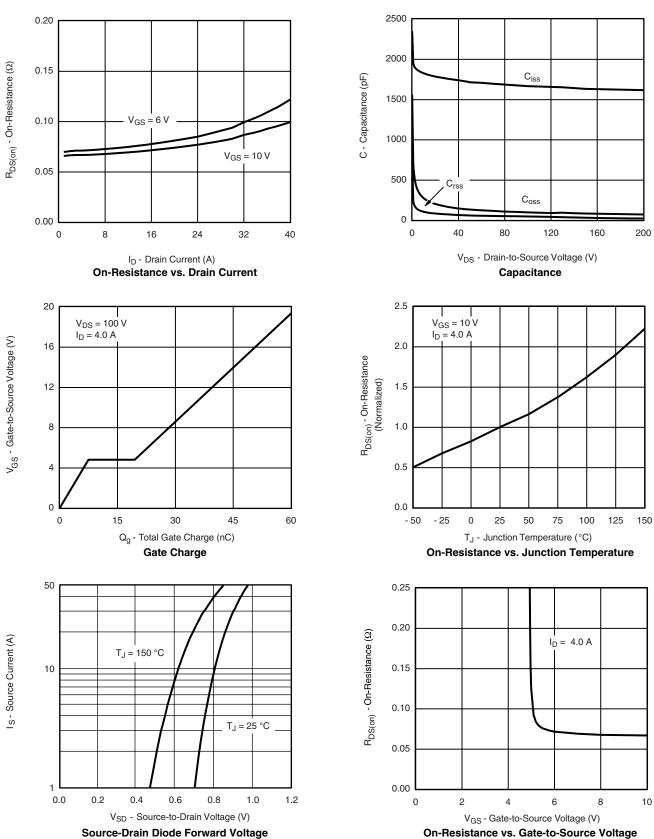
#### TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted





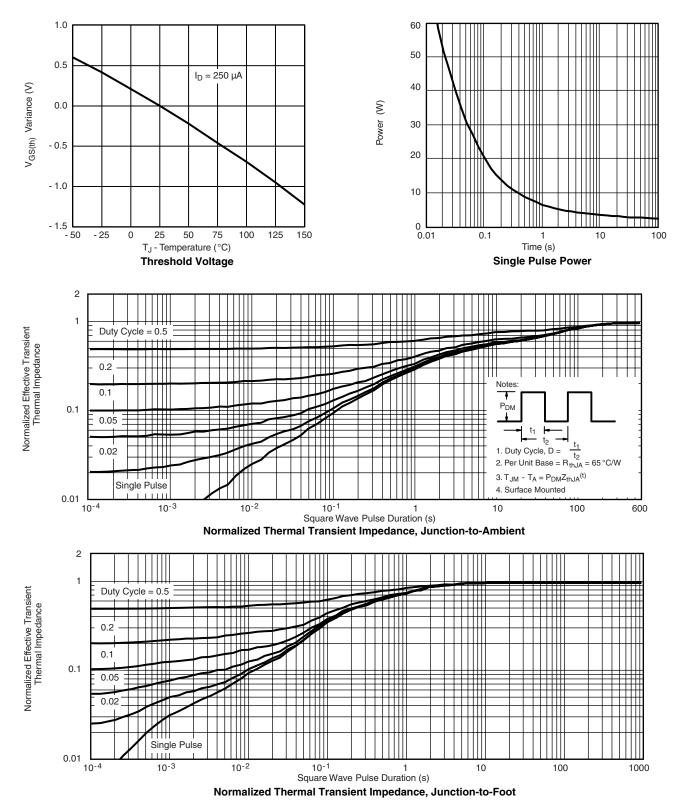


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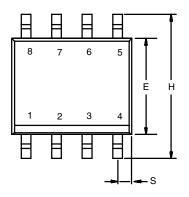


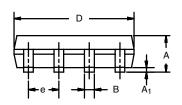
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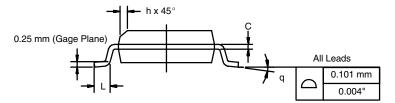




SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012







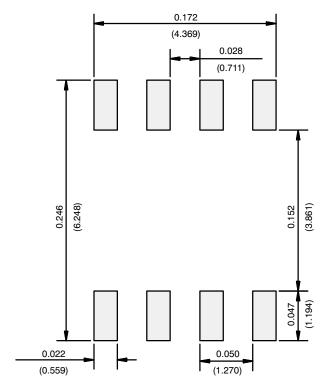
	MILLIM	IETERS	INCHES			
DIM	Min	Max	Min	Max		
Α	1.35	1.75	0.053	0.069		
A <sub>1</sub>	0.10	0.20	0.004	0.008		
В	0.35	0.51	0.014	0.020		
С	0.19	0.25	0.0075	0.010		
D	4.80	5.00	0.189	0.196		
Е	3.80	4.00	0.150	0.157		
е	1.27	BSC	0.050 BSC			
Н	5.80	6.20	0.228	0.244		
h	0.25	0.50	0.010	0.020		
L	0.50	0.93	0.020	0.037		
q	0°	8°	0°	8°		
S	0.44	0.64	0.018	0.026		
ECN: C 06527 Pay 1 11 San 06						

ECN: C-06527-Rev. I, 11-Sep-06

DWG: 5498



### **RECOMMENDED MINIMUM PADS FOR SO-8**



Recommended Minimum Pads Dimensions in Inches/(mm)



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